

Ordering number:6861

PNP/NPN Epitaxial Planar Silicon Transistors



2SB824/2SD1060

50V/5A Switching Applications

Applications

- Suitable for relay drivers, high-speed inverters, converters, and other general large-current switching.

Features

- Low collector-to-emitter saturation voltage :
 $V_{CE(sat)} = (-)0.4V \text{ max} / I_C = (-)3A, I_B = (-)0.3A.$

() : 2SB824

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)5	A
Collector Current (Pulse)	I_{CP}		(-)9	A
Collector Dissipation	P_C	$T_c = 25^\circ C$	30	W
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)40V, I_E = 0$			(-)0.1	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4V, I_C = 0$			(-)0.1	mA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2V, I_C = (-)1A$	70*		280*	
	h_{FE2}	$V_{CE} = (-)2V, I_C = (-)3A$	30			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)5V, I_C = (-)1A$		30		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10V, f = 1MHz$		100		pF
				(160)		pF

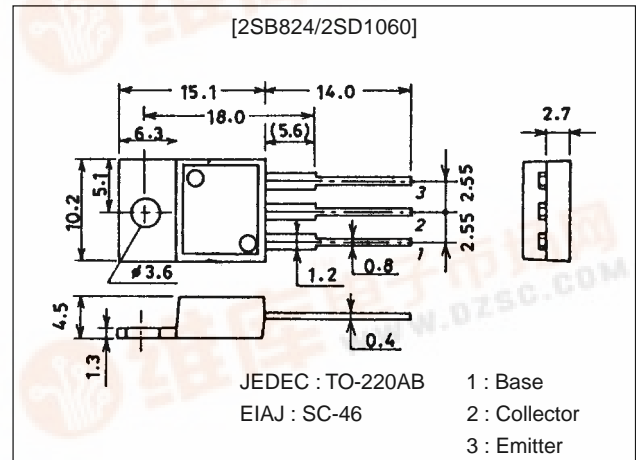
* : The 2SB824/2SD1060 are graded as follows by h_{FE} at 1A :

70	Q	140	100	R	200	140	S	280
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Package Dimensions

unit:mm

2010C



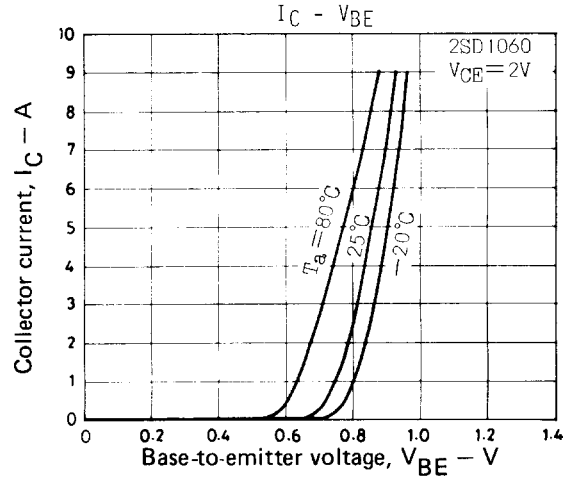
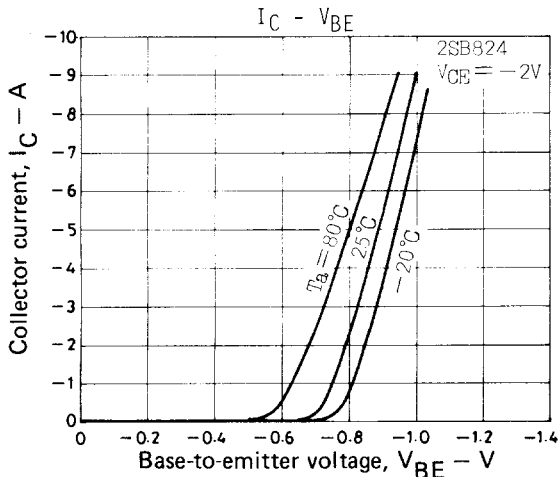
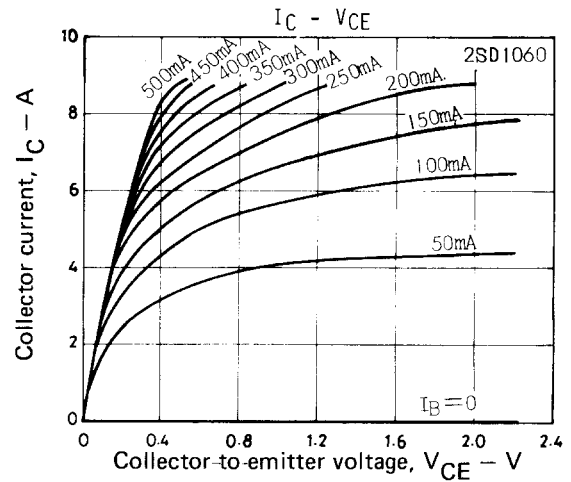
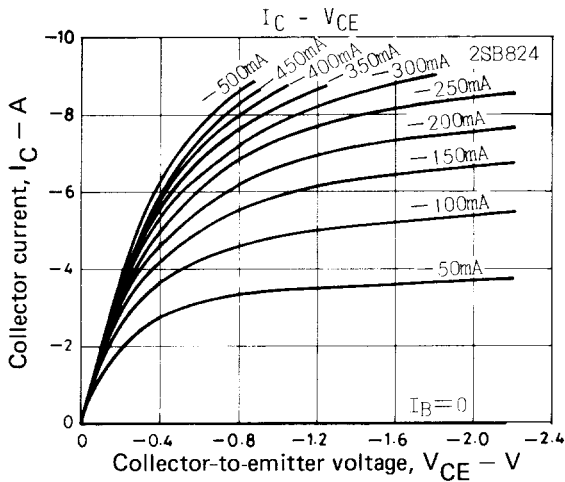
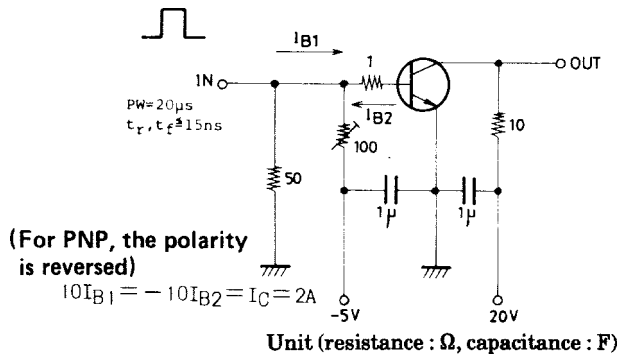
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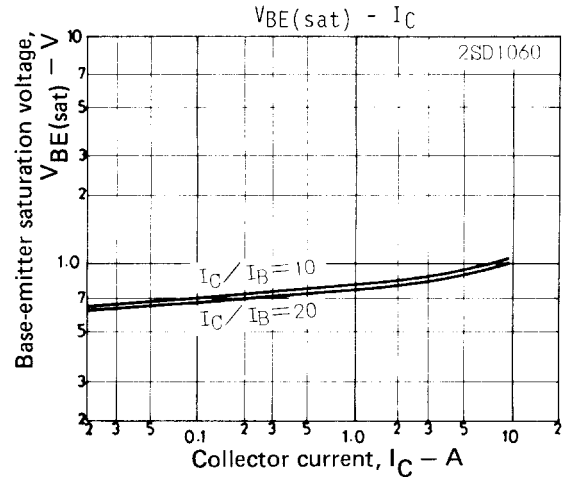
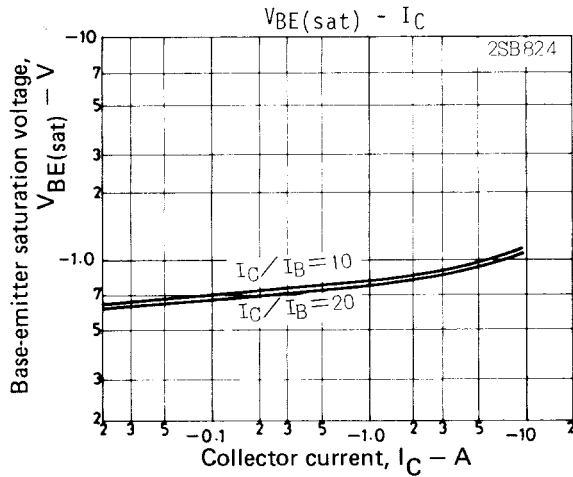
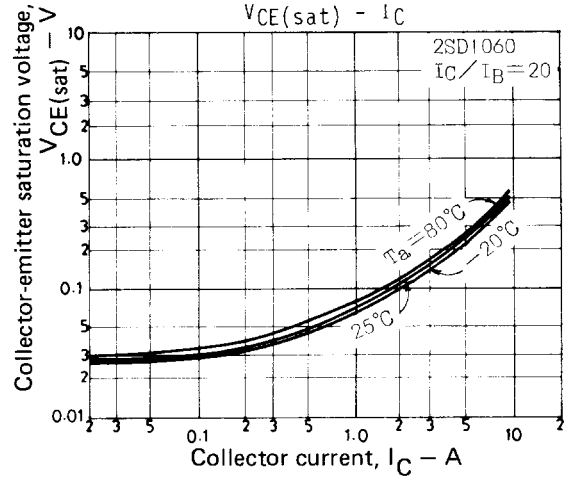
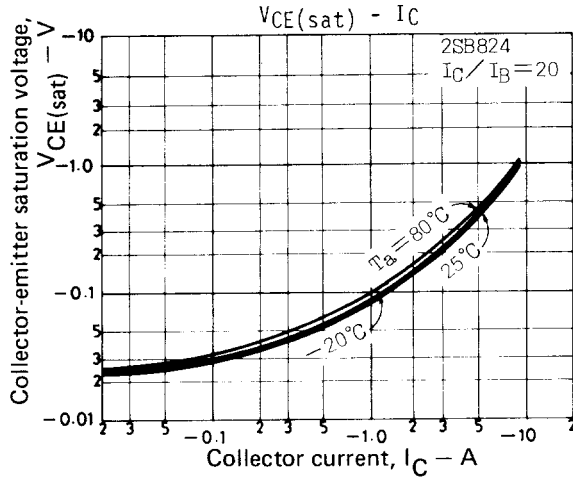
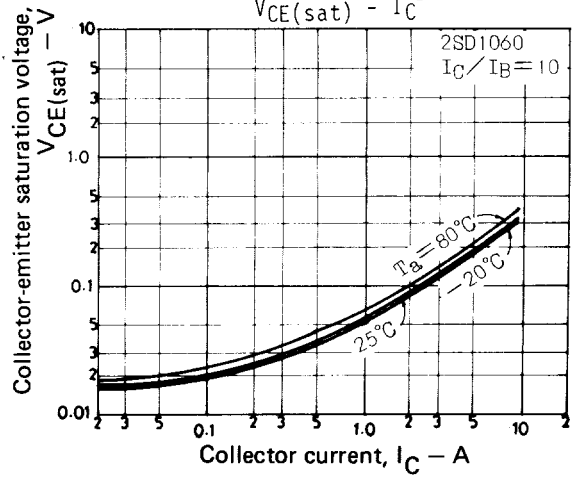
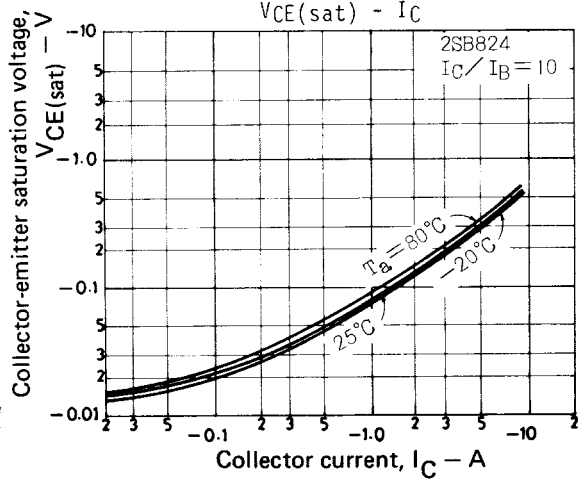
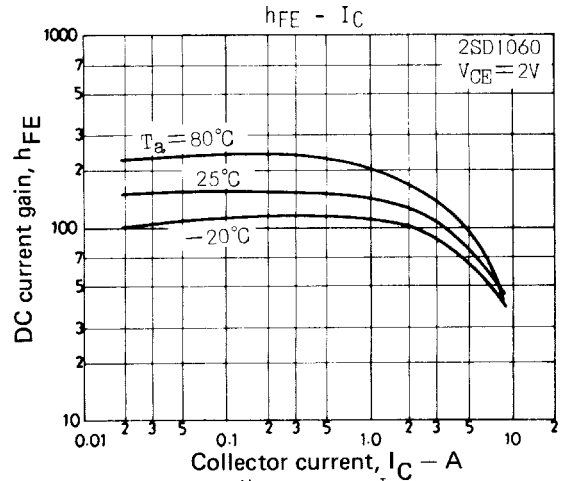
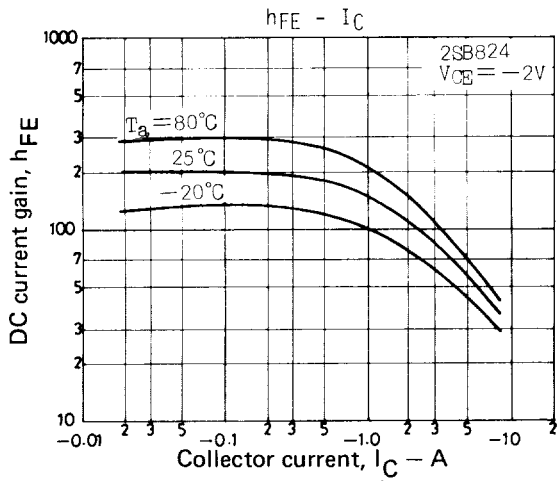
2SB824/2SD1060

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)3A, I_B=(-)0.3A$			(-)0.4	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)1mA, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)1mA, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified test circuit.		0.1		μs
Storage Time	t_{stg}	See specified test circuit.		(0.7)		μs
				1.4		μs
Fall Time	t_f	See specified test circuit.		0.2		μs

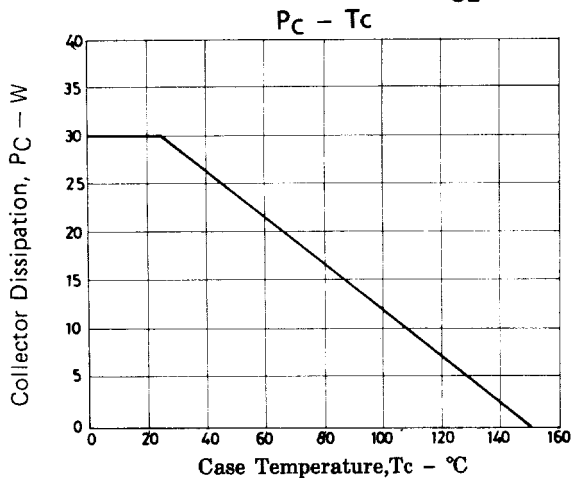
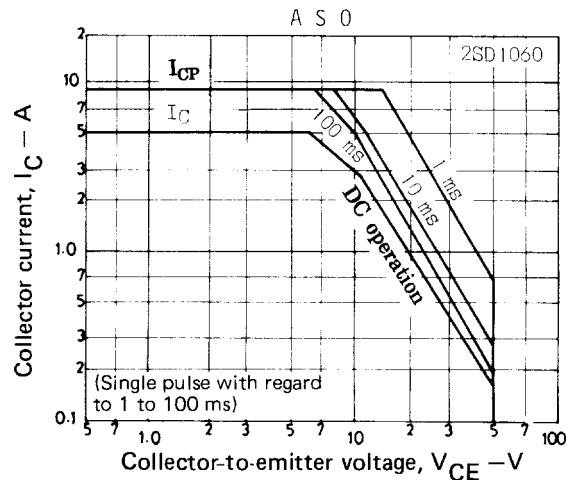
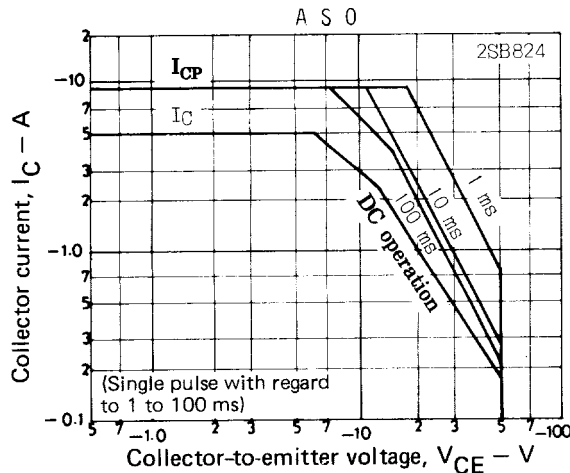
Switching Time Test Circuit



2SB824/2SD1060



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